

REFERENCE

29-Sep-06
ROHM CO.,LTD
Di.Manufacturing Div.

SPICE PARAMETER
RB876W

Characteristic of inner diode

No.	NAME	PARAMETER	UNIT	DATA	
1	IS	Saturation Current	A	4.233E-05	
2	N	Emission Coefficient	-	3.682	
3	RS	Series Resistance	Ω	33.138	
4	IKF	High-injection Knee Current	A	6.608	
5	XTI	Temperature Exponent at IS	-	2	
6	EG	Autivation Energy	eV	0.69	default
7	CJO	Junction Capacitance	F	8.070E-13	
8	M	Granding Coefficient	-	0.149	
9	VJ	Junction Potential	V	0.060	
10	FC	Depletion Capacitance Coefficient	-	0.5	default
11	BV	Breakdown Voltage	V	15	
12	IBV	Breakdown Current	A	1.000E-02	
13	TT	Transit Time	SEC	1.587E-08	